

DATA SHEET

74LV32

Quad 2-input OR gate

Product specification
Supersedes data of 1997 Feb 03
IC24 Data Handbook

1998 Apr 20

Quad 2-input OR gate

74LV32

FEATURES

- Wide operating voltage: 1.0 to 5.5 V
- Optimized for Low Voltage applications: 1.0 to 3.6 V
- Accepts TTL input levels between $V_{CC} = 2.7$ V and $V_{CC} = 3.6$ V
- Typical V_{OLP} (output ground bounce) < 0.8 V at $V_{CC} = 3.3$ V, $T_{amb} = 25^{\circ}\text{C}$.
- Typical V_{OHV} (output V_{OH} undershoot) > 2 V at $V_{CC} = 3.3$ V, $T_{AMB} = 25^{\circ}\text{C}$.
- Output capability: standard
- I_{CC} category: SSI

DESCRIPTION

The 74LV32 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT32.

The 74LV32 provides the 2-input OR function.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}\text{C}$; $t_r = t_f \leq 2.5$ ns

| SYMBOL | PARAMETER | CONDITIONS | TYPICAL | UNIT |
|-------------------|--|------------------------------------|---------|------|
| t_{PHL}/t_{PLH} | Propagation delay nA, nB to nY | $C_L = 15$ pF; $V_{CC} = 3.3$ V | 6 | ns |
| C_I | Input capacitance | | 3.5 | pF |
| C_{PD} | Power dissipation capacitance per gate | $V_I = \text{GND to } V_{CC}^1$ | 16 | pF |

NOTES:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW)
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz; C_L = output load capacitance in pF;
 f_o = output frequency in MHz; V_{CC} = supply voltage in V;
 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

ORDERING INFORMATION

| PACKAGES | TEMPERATURE RANGE | OUTSIDE NORTH AMERICA | NORTH AMERICA | PKG. DWG. # |
|-----------------------------|---|-----------------------|---------------|-------------|
| 14-Pin Plastic DIL | -40°C to $+125^{\circ}\text{C}$ | 74LV32 N | 74LV32 N | SOT27-1 |
| 14-Pin Plastic SO | -40°C to $+125^{\circ}\text{C}$ | 74LV32 D | 74LV32 D | SOT108-1 |
| 14-Pin Plastic SSOP Type II | -40°C to $+125^{\circ}\text{C}$ | 74LV32 DB | 74LV32 DB | SOT337-1 |
| 14-Pin Plastic TSSOP Type I | -40°C to $+125^{\circ}\text{C}$ | 74LV32 PW | 74LV32PW DH | SOT402-1 |

PIN DESCRIPTION

| PIN NUMBER | SYMBOL | NAME AND FUNCTION |
|--------------|----------|-------------------------|
| 1, 4, 9, 12 | 1A – 4A | Data inputs |
| 2, 5, 10, 13 | 1B – 4B | Data inputs |
| 3, 6, 8, 11 | 1Y – 4Y | Data Outputs |
| 7 | GND | Ground (0 V) |
| 14 | V_{CC} | Positive supply voltage |

FUNCTION TABLE

| INPUTS | | OUTPUTS |
|--------|----|---------|
| nA | nB | nY |
| L | L | L |
| L | H | H |
| H | L | H |
| H | H | H |

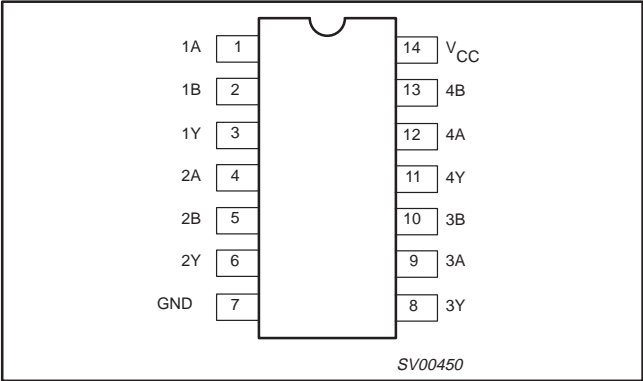
H = HIGH voltage level

L = LOW voltage level

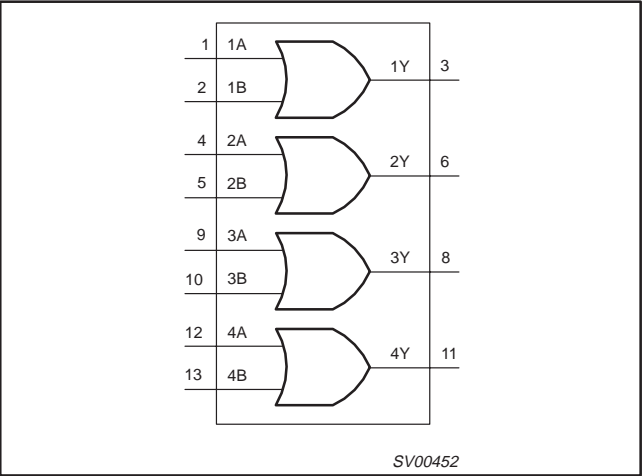
Quad 2-input OR gate

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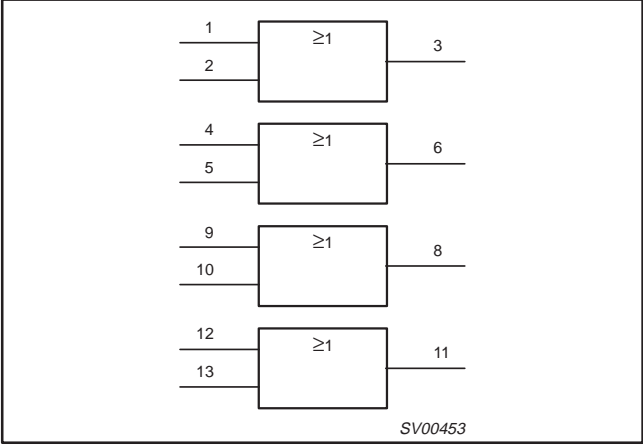
PIN CONFIGURATION



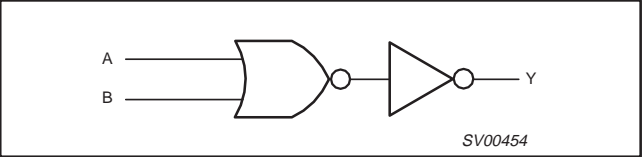
LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



LOGIC DIAGRAM (ONE GATE)



RECOMMENDED OPERATING CONDITIONS

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT |
|---------------------------------|---|--|------------------|------------------|-------------------------|------|
| V _{CC} | DC supply voltage | See Note1 | 1.0 | 3.3 | 5.5 | V |
| V _I | Input voltage | | 0 | – | V _{CC} | V |
| V _O | Output voltage | | 0 | – | V _{CC} | V |
| T _{amb} | Operating ambient temperature range in free air | See DC and AC characteristics | –40 –40 | | +85 +125 | °C |
| t _r , t _f | Input rise and fall times | V _{CC} = 1.0V to 2.0V V _{CC} = 2.0V to 2.7V V _{CC} = 2.7V to 3.6V V _{CC} = 3.6V to 5.5V | – – – – | – – – – | 500 200 100 50 | ns/V |

NOTE:
1. The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 5.5V.

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ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134)

Voltages are referenced to GND (ground = 0V)

| SYMBOL | PARAMETER | CONDITIONS | RATING | UNIT |
|---------------------------------|--|---|-------------------|------|
| V_{CC} | DC supply voltage | | -0.5 to +7.0 | V |
| $\pm I_{IK}$ | DC input diode current | $V_I < -0.5$ or $V_I > V_{CC} + 0.5V$ | 20 | mA |
| $\pm I_{OK}$ | DC output diode current | $V_O < -0.5$ or $V_O > V_{CC} + 0.5V$ | 50 | mA |
| $\pm I_O$ | DC output source or sink current – standard outputs | $-0.5V < V_O < V_{CC} + 0.5V$ | 25 | mA |
| $\pm I_{GND}$, $\pm I_{CC}$ | DC V_{CC} or GND current for types with –standard outputs | | 50 | mA |
| T_{stg} | Storage temperature range | | -65 to +150 | °C |
| P_{TOT} | Power dissipation per package –plastic DIL –plastic mini-pack (SO) –plastic shrink mini-pack (SSOP and TSSOP) | for temperature range: -40 to +125°C above +70°C derate linearly with 12mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K | 750 500 400 | mW |

NOTE:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

| SYMBOL | PARAMETER | TEST CONDITIONS | LIMITS | | | | | UNIT |
|-----------------|---|---|-----------------------|------------------|-----------------------|-----------------------|-----------------------|------|
| | | | -40°C to +85°C | | | -40°C to +125°C | | |
| | | | MIN | TYP ¹ | MAX | MIN | MAX | |
| V _{IH} | HIGH level Input voltage | V _{CC} = 1.2V | V _{CC} | 0.6 | | V _{CC} | | V |
| | | V _{CC} = 2.0V | 1.4 | | | 1.4 | | |
| | | V _{CC} = 2.7 to 3.6V | 2.0 | | | 2.0 | | |
| | | V _{CC} = 4.5 to 5.5V | 0.7 * V _{CC} | | | 0.7 * V _{CC} | | |
| V _{IL} | LOW level Input voltage | V _{CC} = 1.2V | | 0.4 | GND | | GND | V |
| | | V _{CC} = 2.0V | | | 0.6 | | 0.6 | |
| | | V _{CC} = 2.7 to 3.6V | | | 0.8 | | 0.8 | |
| | | V _{CC} = 4.5 to 5.5 | | | 0.3 * V _{CC} | | 0.3 * V _{CC} | |
| V _{OH} | HIGH level output voltage; all outputs | V _{CC} = 1.2V; V _I = V _{IH} or V _{IL} ; -I _O = 100μA | | 1.2 | | | | V |
| | | V _{CC} = 2.0V; V _I = V _{IH} or V _{IL} ; -I _O = 100μA | 1.8 | 2.0 | | 1.8 | | |
| | | V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; -I _O = 100μA | 2.5 | 2.7 | | 2.5 | | |
| | | V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; -I _O = 100μA | 2.8 | 3.0 | | 2.8 | | |
| | | V _{CC} = 4.5V; V _I = V _{IH} or V _{IL} ; -I _O = 100μA | 4.3 | 4.5 | | 4.3 | | |
| V _{OH} | HIGH level output voltage; STANDARD outputs | V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; -I _O = 6mA | 2.40 | 2.82 | | 2.20 | | V |
| | | V _{CC} = 4.5V; V _I = V _{IH} or V _{IL} ; -I _O = 12mA | 3.60 | 4.20 | | 3.50 | | |
| V _{OL} | LOW level output voltage; all outputs | V _{CC} = 1.2V; V _I = V _{IH} or V _{IL} ; I _O = 100μA | | 0 | | | | V |
| | | V _{CC} = 2.0V; V _I = V _{IH} or V _{IL} ; I _O = 100μA | | 0 | 0.2 | | 0.2 | |
| | | V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; I _O = 100μA | | 0 | 0.2 | | 0.2 | |
| | | V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = 100μA | | 0 | 0.2 | | 0.2 | |
| | | V _{CC} = 4.5V; V _I = V _{IH} or V _{IL} ; I _O = 100μA | | 0 | 0.2 | | 0.2 | |
| V _{OL} | LOW level output voltage; STANDARD outputs | V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = 6mA | | 0.25 | 0.40 | | 0.50 | V |
| | | V _{CC} = 4.5V; V _I = V _{IH} or V _{IL} ; I _O = 12mA | | 0.35 | 0.55 | | 0.65 | |
| I _I | Input leakage current | V _{CC} = 5.5V; V _I = V _{CC} or GND | | | 1.0 | | 1.0 | μA |

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DC ELECTRICAL CHARACTERISTICS (Continued)

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

| SYMBOL | PARAMETER | TEST CONDITIONS | LIMITS | | | | | UNIT |
|------------------|-------------------------------------|---|----------------|------------------|------|-----------------|-----|------|
| | | | -40°C to +85°C | | | -40°C to +125°C | | |
| | | | MIN | TYP ¹ | MAX | MIN | MAX | |
| I _{CC} | Quiescent supply current; SSI | V _{CC} = 5.5V; V _I = V _{CC} or GND; I _O = 0 | | | 20.0 | | 40 | μA |
| ΔI _{CC} | Additional quiescent supply current | V _{CC} = 2.7V to 3.6V; V _I = V _{CC} -0.6V | | | 500 | | 850 | μA |

NOTES:

1. All typical values are measured at T_{amb} = 25°C.

AC CHARACTERISTICS

GND = 0V; t_r = t_f = 2.5ns; C_L = 50pF; R_L = 500Ω

| SYMBOL | PARAMETER | WAVEFORM | CONDITION | LIMITS -40 to +85 °C | | | LIMITS -40 to +125 °C | | UNIT |
|------------------------------------|-----------------------------------|--------------|---------------------|-------------------------|------------------|-----|--------------------------|-----|------|
| | | | | MIN | TYP ¹ | MAX | MIN | MAX | |
| | | | V _{CC} (V) | | | | | | |
| t _{PHL} /t _{PLH} | Propagation delay nA, nB to nY | Figures 1, 2 | 1.2 | | 40 | | | | ns |
| | | | 2.0 | | 14 | 22 | | 28 | |
| | | | 2.7 | | 10 | 16 | | 20 | |
| | | | 3.0 to 3.6 | | 8 ² | 13 | | 16 | |
| | | | 4.5 to 5.5 | | | 10 | | 13 | |

NOTES:

1. Unless otherwise stated, all typical values are measured at T_{amb} = 25°C
2. Typical values are measured at V_{CC} = 3.3 V.

AC WAVEFORMS

V_M = 1.5 V at V_{CC} ≥ 2.7 V and ≤ 3.6 V;
V_M = 0.5 V × V_{CC} at V_{CC} < 2.7 V and ≥ 4.5 V;
V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

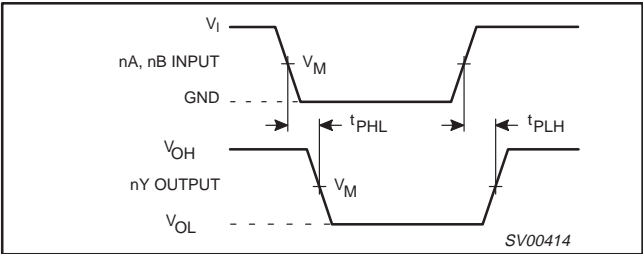


Figure 1. Input (nA, nB) to output (nY) propagation delays and output transition times.

TEST CIRCUIT

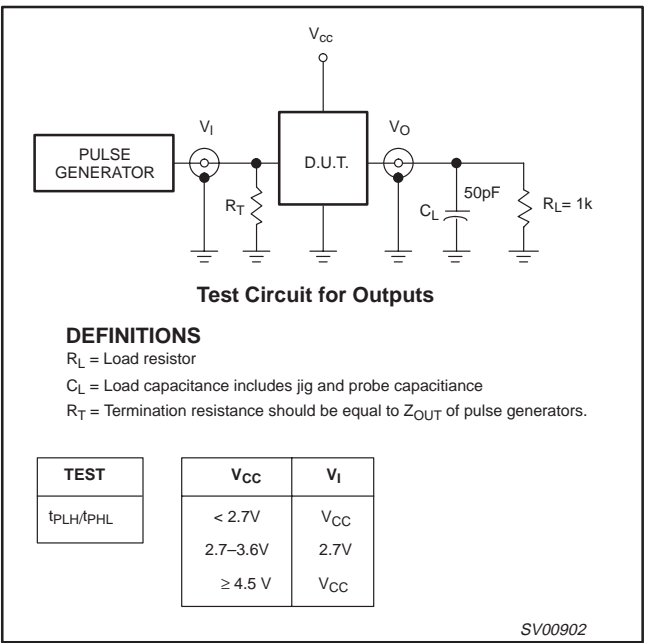


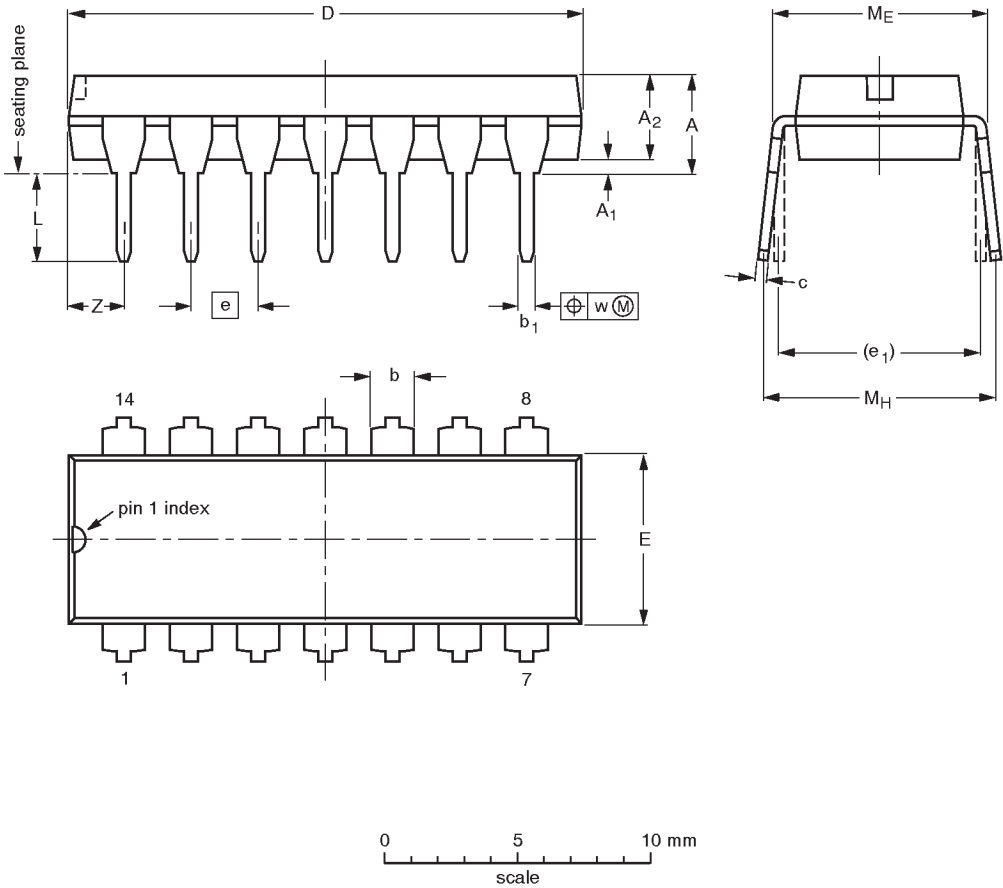
Figure 2. Load circuitry for switching times.

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DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1




DIMENSIONS (inch dimensions are derived from the original mm dimensions)

| UNIT | A max. | A ₁ min. | A ₂ max. | b | b ₁ | c | D ⁽¹⁾ | E ⁽¹⁾ | e | e ₁ | L | M _E | M _H | w | Z ⁽¹⁾ max. |
|--------|-----------|------------------------|------------------------|----------------|----------------|----------------|------------------|------------------|------|----------------|--------------|----------------|----------------|-------|--------------------------|
| mm | 4.2 | 0.51 | 3.2 | 1.73 1.13 | 0.53 0.38 | 0.36 0.23 | 19.50 18.55 | 6.48 6.20 | 2.54 | 7.62 | 3.60 3.05 | 8.25 7.80 | 10.0 8.3 | 0.254 | 2.2 |
| inches | 0.17 | 0.020 | 0.13 | 0.068 0.044 | 0.021 0.015 | 0.014 0.009 | 0.77 0.73 | 0.26 0.24 | 0.10 | 0.30 | 0.14 0.12 | 0.32 0.31 | 0.39 0.33 | 0.01 | 0.087 |

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

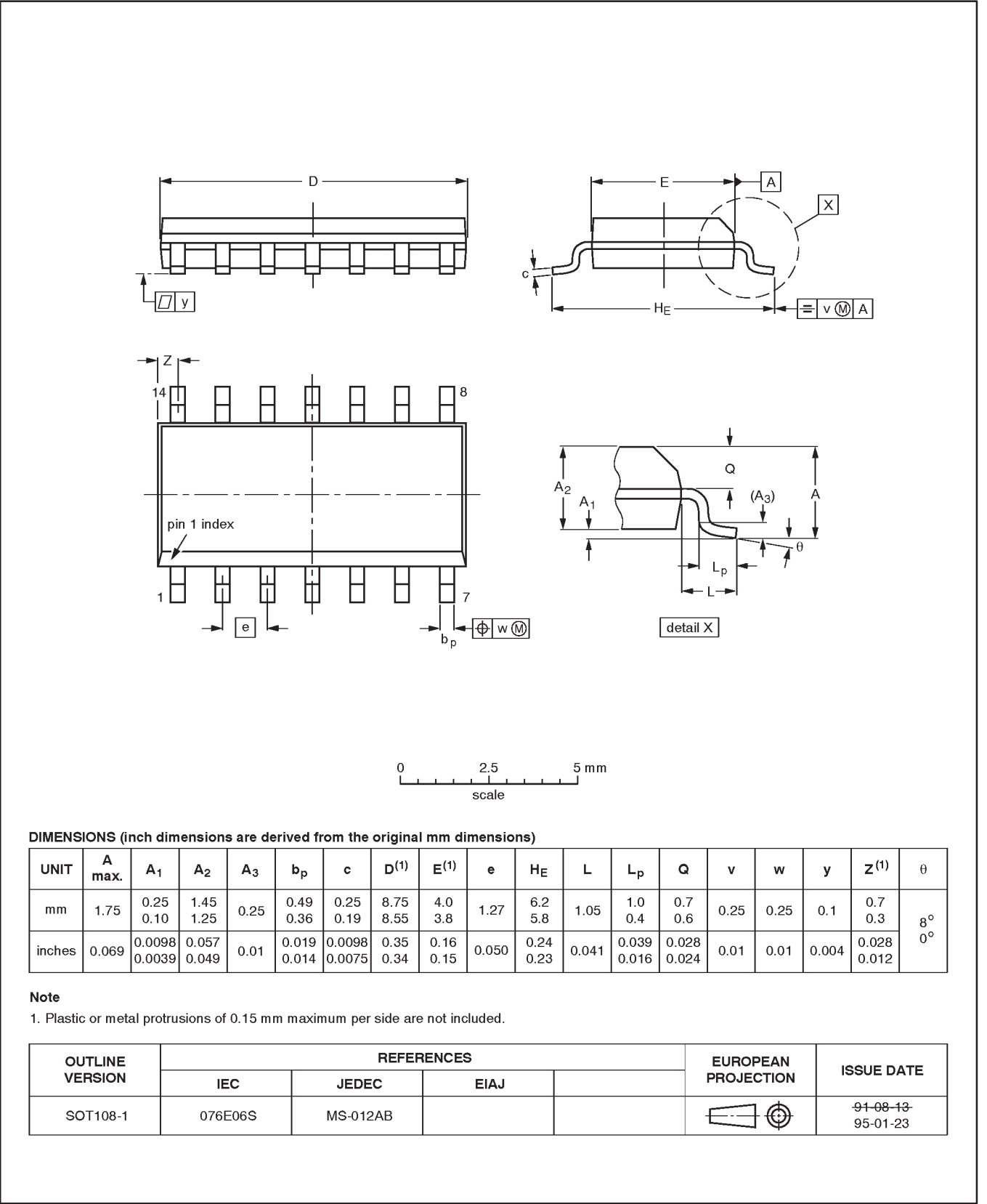
| OUTLINE VERSION | REFERENCES | | | | EUROPEAN PROJECTION | ISSUE DATE |
|--------------------|------------|----------|------|--|---|----------------------|
| | IEC | JEDEC | EIAJ | | | |
| SOT27-1 | 050G04 | MO-001AA | | |  | 92-11-17 95-03-11 |

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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1

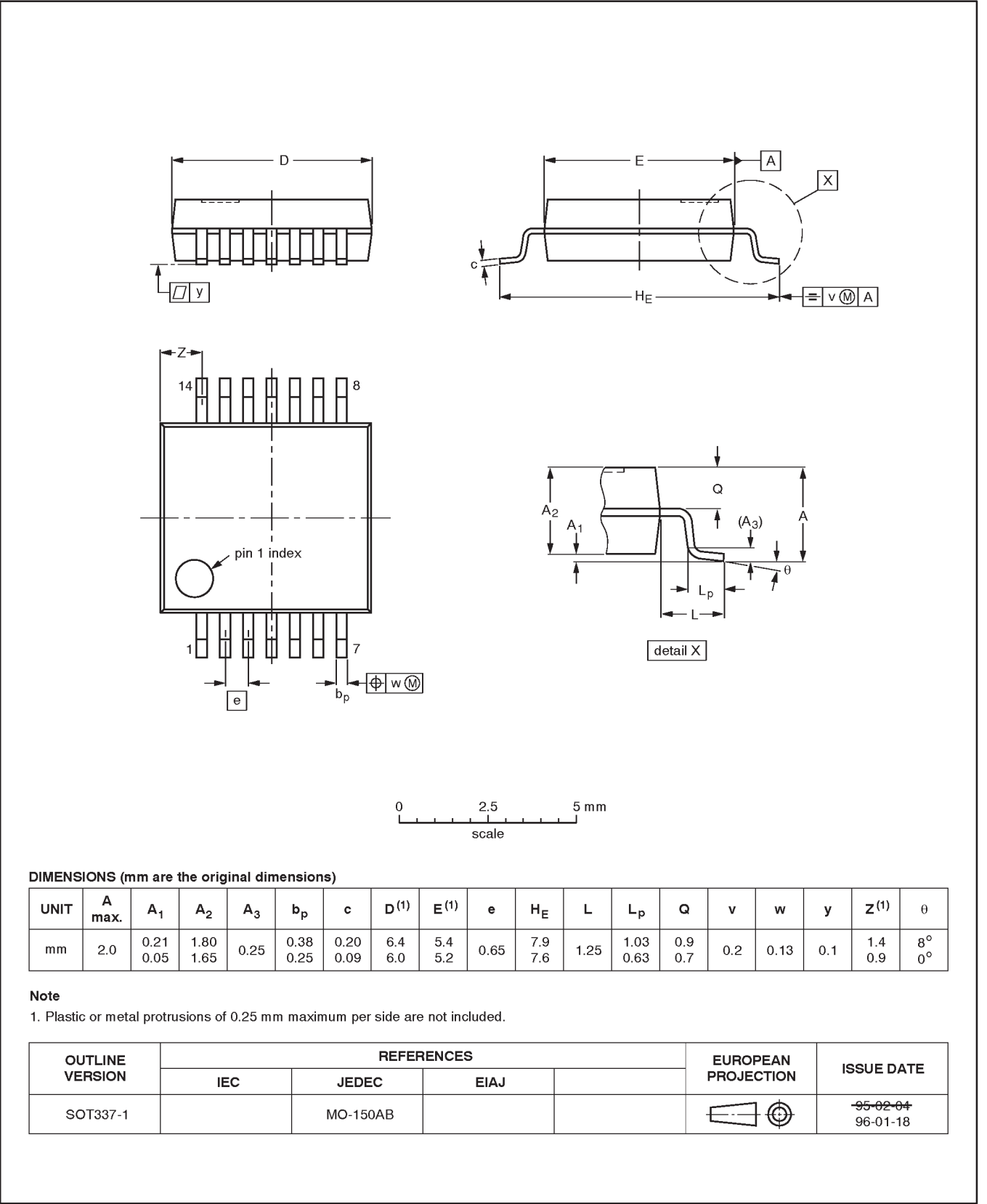


Quad 2-input OR gate

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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1

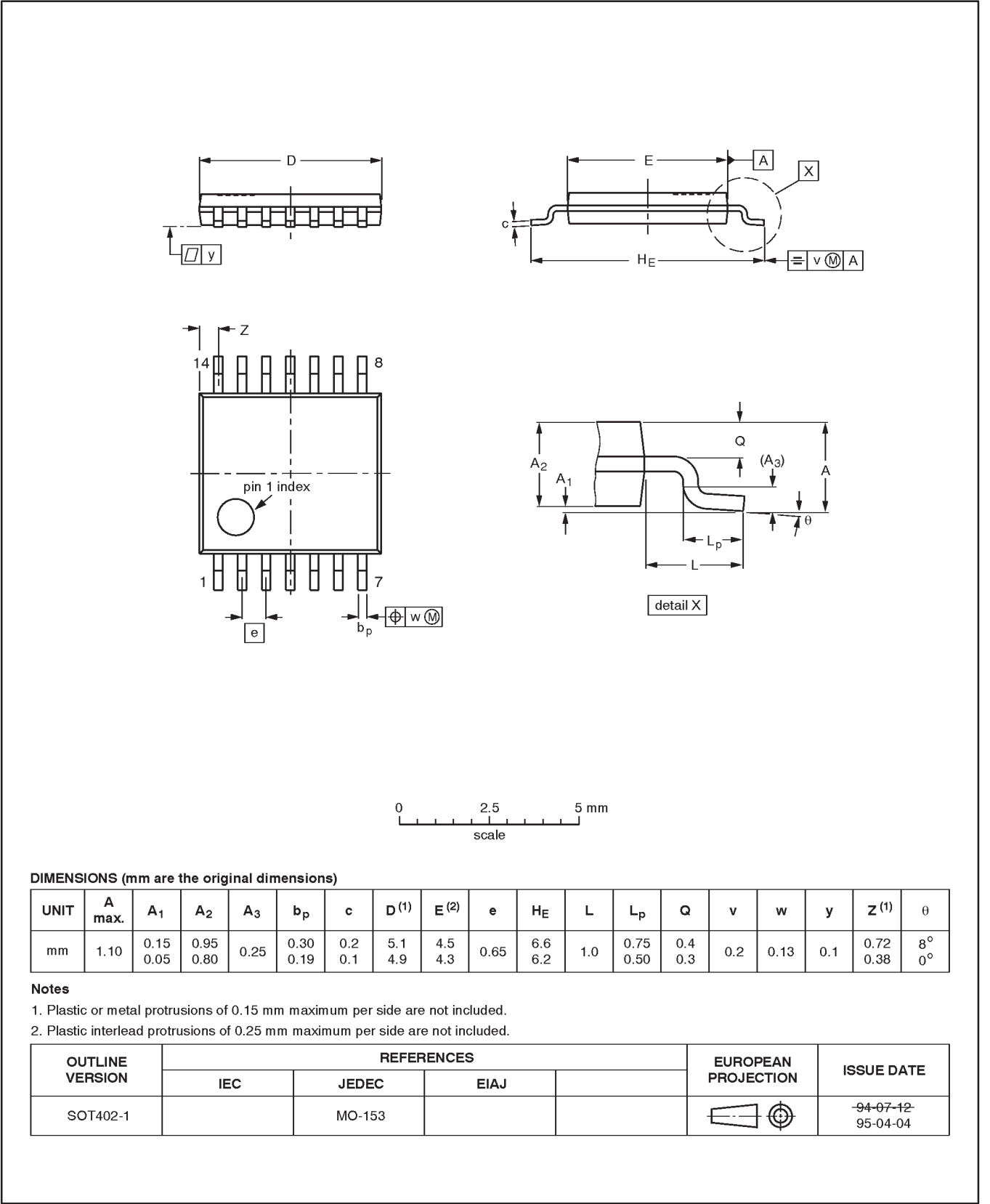


Quad 2-input OR gate

74LV32

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



Quad 2-input OR gate

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| DEFINITIONS | | |
|---------------------------|------------------------|--|
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